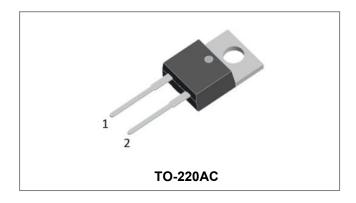






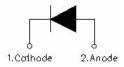
# **SUR1560 ULTRAFAST RECTIFIER**



### **Features**

- Ultra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

# **Circuit Diagram**



# **Applications**

- Switching Power Supply
- Power Switching Circuits
- General Purpose

## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	600	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=100°C, rectangular wave form	15	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse	125	Α

## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@15A, Pulse, T <sub>J</sub> = 25°C	1.35	2.4	V
	V <sub>F2</sub>	@15A, Pulse, T <sub>J</sub> = 100°C	-	2.0	V
Reverse Current*	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ $T_J = 25^{\circ}C$	0.03	5	μA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 100^{\circ}C$	-	50	μA
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =500mA, I <sub>R</sub> =1A,and I <sub>m</sub> =250mA	42	50	ns

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%



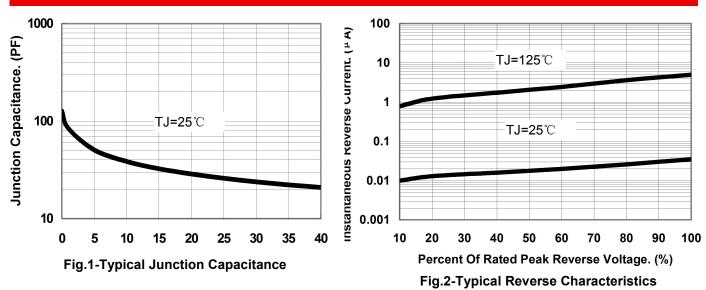




# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>θ</sub> Jc	DC operation	4	°C/W
Approximate Weight	wt	-	1.6	g
Case Style	TO-220AC			

## **Ratings and Characteristics Curves**



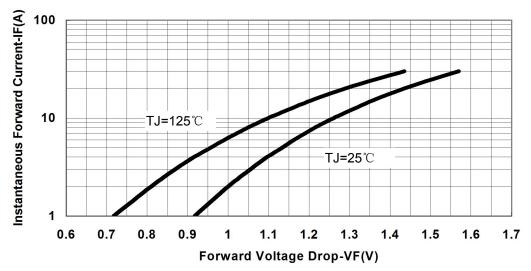


Fig.3-Typical Forward Voltage Drop Characteristics

<sup>•</sup> China - Germany - Korea - Singapore - United States •

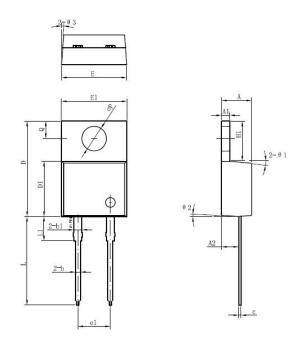
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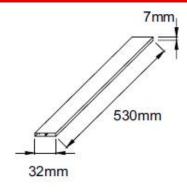


## **Mechanical Dimensions TO-220AC**

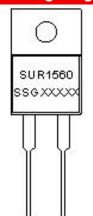


Symbol	Dimensions in millimeters			
_	Min.	Typical	Max.	
Α	4.47	4.70	4.85	
A1	1.17	1.27	1.37	
A2	2.52	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
С	0.31	0.38	0.61	
D	14.64	14.94	15.24	
D1	8.50	8.07	8.90	
E	10.01	10.16	10.31	
E1	9.98	10.18	10.38	
e1	4.98	5.08	5.18	
H1	6.04	6.24	6.44	
L	13.00	13.86	14.08	
L1	3.56	3.80	3.96	
ФР	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		5°		
Θ2		4°		
Θ3		4°		

# **Tube Specification**



# **Marking Diagram**



Where XXXXX is YYWWL

SUR = Device Type 15 = Forward Current (15A) 60 = Reverse Voltage(600V)

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

**Cautions:** Molding resin Epoxy resin UL:94V-0

# **Ordering Information**

Device	Package	Shipping	
SUR1560	TO-220AC (Pb-Free)	50 pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •







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